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L22: Entry 19 of 21 File: USPT Jul 5, 1994

US-PAT-NO: 5326659

DOCUMENT-IDENTIFIER: US 5326659 A

TITLE: Method for making masks

DATE-ISSUED: July 5, 1994

INVENTOR-INFORMATION:

NAME CITY STATE ZIP CODE COUNTRY

Liu; Yong Berkeley CA Zakhor; Avideh Berkeley CA

Neureuther; Andrew Berkeley CA

ASSIGNEE-INFORMATION:

NAME CITY STATE ZIP CODE COUNTRY TYPE CODE

Regents of the University of California Oakland CA 02

APPL-NO: 07/ 847757 [PALM]
DATE FILED: March 5, 1992

INT-CL: [05] G03F 9/00

US-CL-ISSUED: 430/5; 430/320, 430/321, 395/800

US-CL-CURRENT: 430/5; 430/320, 430/321

FIELD-OF-SEARCH: 430/5, 430/320, 430/321, 395/800

PRIOR-ART-DISCLOSED:

U.S. PATENT DOCUMENTS

Search Selected Search ALL Clear

PAT-NO ISSUE-DATE

PATENTEE-NAME US-CL

4593351

June 1986

Hong et al.

395/800

OTHER PUBLICATIONS

SPIE vol. 1264 Optical/Laser Microlithography III (1990), article entitled "Optimal Binary Image Design for Optical Lithography," by Yong Liu, et al., pp. 401-412. Heidelberg Coloquium on Glassy Dynamics and Optimization, Berlin, 1987, entitled "A Pedestrian Review of the Theory and Application of the Simulated Annealing Algorithm," by Emile H. L. Aarts, et al., pp. 288-306.

Proceedings of 24th Conference on Decision and Control, Ft. Lauderdale, Florida, Dec. 1985, entitled "A Tutorial Survey of Theory and Applications of Simulated Annealing," by Bruce Hajek.

Science, May 13, 1983, vol. 220, No. 4598, pp. 339-348, article entitled "Optimization by Simulated Annealing," by S. Kirkpatrick, et al.

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ART-UNIT: 157

PRIMARY-EXAMINER: McCamish; Marion E.

ASSISTANT-EXAMINER: Chapman; Mark A.

ATTY-AGENT-FIRM: Ware and Freidenrich

ABSTRACT:

A method for making a mask for optical lithography or other projection printing, wherein the mask is represented by a mask pattern, is disclosed herein. The mask provides a substantially binary output image on the surface of a wafer as light is applied to the mask. Light passes through the mask and onto a wafer at varying intensities, such intensities represented by output intensity values, the threshold values of which produce output images within predetermined constraints. The method includes the steps of defining sampling points which are representative of the binary output image. These sampling points are used in defining local objective functions, which are combined to give a total objective function. The present invention further includes the steps of adjusting the mask pattern to provide for minimization by optimization of the objective function, transferring the mask pattern to a mask generating machine to generate a mask, and generating a mask. Moreover, the present invention includes the step of providing an output image which is focused on a plurality of optical planes. Furthermore, the present invention includes the step isolating three of the plurality of optical planes so that their output intensity is optimized at these planes, thereby producing a focusing plane shift at the center focal plane as well as producing an extended depth of focus.

11 Claims, 39 Drawing figures

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DB=PGPB,USPT,JPAB; PLUR=YES; OP=OR				
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	L32	L31 and 115	17	
	L31	L30 and (entropy or thermodynamic)	19	
	L30	L5 and 119	103	
	L29	126 and L28	1	
	L28	(thermodynamic or entropy) same schedul\$	110	
	L27	L26 and (entropy or thermodynamic)	18	
	L26	L19 and 115	77	
	L25	L20 and 115	77	
	L24	L19 and entropy	8	
	L23	L22 and entropy	2	
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	L21	L20 and (thermal\$ or thermodynamic)	29	
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	L19	simulat\$ same anneal\$ same schedul\$	197	
	L18	L17 and (therma\$ or thermodynamic)	20	
	L17	L16 and schedul\$	36	
	L16	19 and L15	87	
	L15	temperature same parameter	113635	
	L14	L13 and parameter	16	
	L13	L12 and temperature	17	
	L12	L11 and local\$	18	
	L11	L9 and thermal\$ and schedul\$	22	
	L10	L9 thermal\$ and schedul\$	16683	
	L9	12 same 15	210	
	L8	L7 and schedul\$	57	
	L7	L6 and thermal\$	145	
	L6	l2 and L5	651	
	L5	combinat\$ same (optimal or optimization or optimizer or optim\$3)	60347	
	L4	L2 and l1	2431	
	L3	L2 not 11	429	
	L2	simulat\$ same anneal\$	2860	
	L1	simulat\$ with anneal\$	2431	

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